

## **60V PNP SMALL SIGNAL TRANSISTOR IN SOT323**

### **Features**

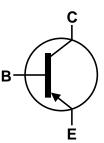
- BV<sub>CEO</sub> > -60V
- I<sub>C</sub> = -600mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary NPN Type: MMST2222A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

## **Mechanical Data**

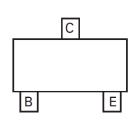
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
  Solderable per MIL-STD-202, Method 208 (2)
- Weight: 0.006 grams (Approximate)







Device Symbol



Pin-Out Top View

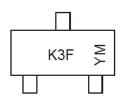
### Ordering Information (Notes 4 & 5)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMST2907A-7-F	Active	AEC-Q101	K3F	7	8	3,000
MMST2907AQ-7	Active	Automotive	K3F	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



K3F = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: A = 2013) M or  $\overline{M}$  = Month (ex: 9 = September)

#### Date Code Key

Year	201	0	2011	2012	2013	2014	2015	201	6 20	17	2018	2019	2020
Code	Х		Υ	Z	Α	В	С	D	[	=	F	G	Н
Month	า	Ja	n Fel	o Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	!	1	2	3	4	5	6	7	8	9	0	N	D



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Collector Current	Ic	-600	mA

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	$P_{D}$	200	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 6. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

# **Thermal Characteristics and Derating Information**

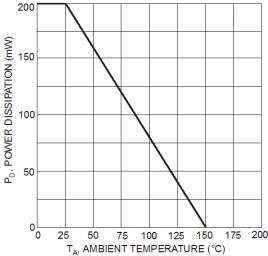


Fig. 1 Max Power Dissipation vs. Ambient Temperature



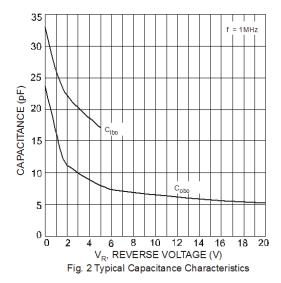
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

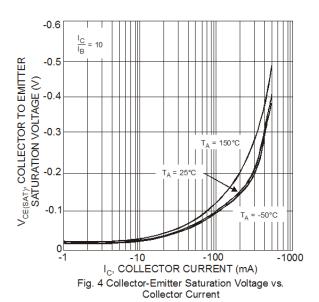
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)					
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-60		V	$I_C = -10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	-60		V	$I_C = -10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5		V	$I_E = -10\mu A, I_C = 0$
Collector Base Cutoff Current	I <sub>CBO</sub>		-10	nΑ μΑ	V <sub>CB</sub> = -50V, I <sub>E</sub> = 0 V <sub>CB</sub> = -50V, I <sub>E</sub> = 0, T <sub>A</sub> = +125°C
Collector Cutoff Current	I <sub>CEX</sub>		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
Base Cutoff Current	I <sub>BL</sub>		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
ON CHARACTERISTICS (Note 8)					
DC Current Gain	h <sub>FE</sub>	75 100 100 100 50	 	_	$\begin{split} I_{C} &= -100 \mu A, \ V_{CE} = -10 V \\ I_{C} &= -1 m A, \ V_{CE} = -10 V \\ I_{C} &= -10 m A, \ V_{CE} = -10 V \\ I_{C} &= -150 m A, \ V_{CE} = -10 V \\ I_{C} &= -500 m A, \ V_{CE} = -10 V \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	-0.4 -1.6	V	$I_C = -150 \text{mA}, I_B = -15 \text{mA}$ $I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	1.3 2.6	V	$I_C = -150 \text{mA}, I_B = -15 \text{mA}$ $I_C = -500 \text{mA}, I_B = -50 \text{mA}$
SMALL SIGNAL CHARACTERISTICS				•	
Output Capacitance	C <sub>OBO</sub>		8	pF	$V_{CB} = -10V$ , $f = 1.0MHz$ , $I_E = 0$
Input Capacitance	C <sub>IBO</sub>		30	pF	$V_{EB} = -2V$ , $f = 1.0MHz$ , $I_C = 0$
Current Gain-Bandwidth Product	f⊤	200		MHz	$V_{CE} = -20V, I_{C} = -50mA,$ f = 100MHz
SWITCHING CHARACTERISTICS					
Turn-On Time	t <sub>ON</sub>	_	45	ns	V <sub>CC</sub> = -30V, I <sub>C</sub> = -150mA,
Delay Time	t <sub>D</sub>	_	10	ns	I <sub>B1</sub> = -15mA
Rise Time	t <sub>R</sub>	_	40	ns	IBI - IOIIIA
Turn-Off Time	toff	_	100	ns	$V_{CC} = -6V, I_{C} = -150mA,$
Storage Time	t <sub>S</sub>	_	80	ns	$I_{B1} = I_{B2} = -15 \text{mA}$
Fall Time	t <sub>F</sub>	_	30	ns	IRI – IR7 – - IOIIIV

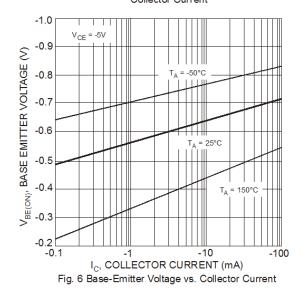
Note: 8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

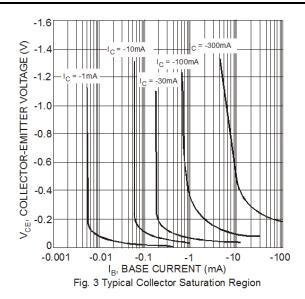


## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)









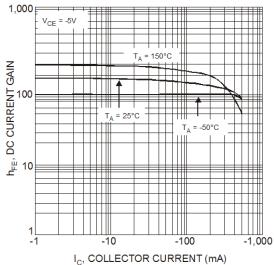


Fig. 5 DC Current Gain vs. Collector Current

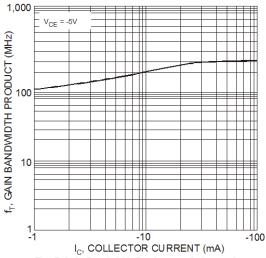


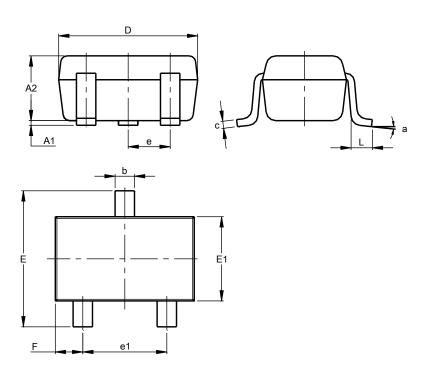
Fig. 7 Gain Bandwidth Product vs. Collector Current



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT323**

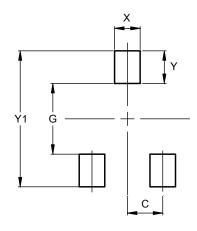


SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
C	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C	).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°	_					
All Dimensions in mm								

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT323**



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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